

Fast Silicon Rectifier

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Nominal current

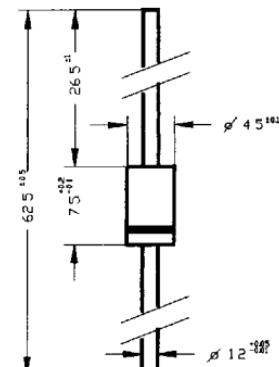
1,2 A

Repetitive peak reverse voltage 1000..2500 V

Plastic case = DO-13

Package material according UL94-V0

Weight approx. 1 g



All dimensions in mm

Maximum ratings

		SHG 1	1.5	2	2.5	V
Repetitive peak reverse voltage	V_{RRM}	1000	1500	2000	2500	V
Surge forward current half cycle sine wave starting at $T_j = 25^\circ\text{C}$	I_{FSM}			6		A
Junction temperature	T_j			150		$^\circ\text{C}$
Operating temperature	T_A			-40..+150		$^\circ\text{C}$
Storage temperature	T_s			-40..+150		$^\circ\text{C}$

Characteristics

Nominal current at half wave rectif. with resistive load;
 $T_A = 50^\circ\text{C}$

I_{FAV} 200 mA

Forward voltage
at $I_f = 3 \text{ A}$, $T_j = 25^\circ\text{C}$

V_F < 4.0 V

Leakage current at
 V_{RRM} , $T_j = 25^\circ\text{C}$

I_R < 10 μA

Reverse recovery time
 $I_f = 100 \text{ mA}$

t_{rr} < 1 μs

Thermal resistance

R_{thu} < 60 K/W₁₎

¹⁾Valid, if leads are kept at ambient temperature at a distance of 10mm from case